



HER201G THRU HER208G

HIGH EFFICIENCY GLASS PASSIVATED RECTIFIER

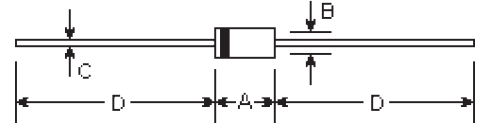
Reverse Voltage - 50 to 1000 Volts

Forward Current - 2.0 Amperes

Features

- Low power loss, high efficiency
- Low leakage
- Low forward voltage drop
- High current capability
- High speed switching
- High current surge
- High reliability

DO-15



Mechanical Data

- **Case:** Molded plastic
- **Epoxy:** UL94V-0 rate flame retardant
- **Lead:** MIL-STD-202E method 208C guaranteed
- **Mounting Position:** Any
- **Weight:** 0.014 ounce, 0.395 gram

DIMENSIONS					
DIM	inches		mm		Note
	Min.	Max.	Min.	Max.	
A	0.228	0.299	5.8	7.6	
B	0.102	0.142	2.6	3.6	φ
C	0.028	0.034	0.71	0.86	φ
D	1.000	-	25.40	-	

Maximum Ratings and Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	Symbols	HER 201G	HER 202G	HER 203G	HER 204G	HER 205G	HER 206G	HER 207G	HER 208G	Units
Maximum repetitive peak reverse voltage	V _{RRM}	50	100	200	300	400	600	800	1000	Volts
Maximum RMS voltage	V _{RMS}	35	70	140	210	280	420	560	700	Volts
Maximum DC blocking voltage	V _{DC}	50	100	200	300	400	600	800	1000	Volts
Maximum average forward rectified current 0.375" (9.5mm) lead length at T _A =50°C	I _(AV)	2.0								Amps
Peak forward surge current, 8.3mS single half sine-wave superimposed on rated load (MIL-STD-750D 4066 method)	I _{FSM}	60.0								Amps
Maximum instantaneous forward voltage at 2.0A DC	V _F	1.0			1.3		1.5	1.7		Volts
Maximum full load reverse current average, full cycle 0.375" (9.5mm) lead length at T _L =55°C	I _{R(AV)}	100.0								μ A
Maximum DC reverse current at rated DC blocking voltage T _A =25°C	I _R	5.0								μ A
Maximum reverse recovery time (Note 1)	T _{rr}	50.0					75.0			nS
Typical junction capacitance (Note 2)	C _J	30					20			p F
Operating and storage temperature range	T _J , T _{STG}	-65 to +150								°C

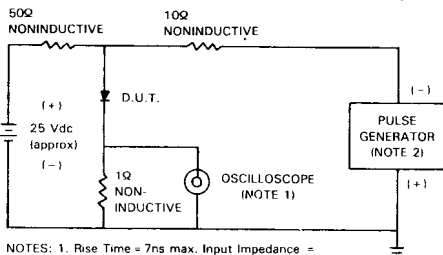
Notes:

(1) Test conditions: $I_F=0.5\text{A}$, $I_R=1.0\text{A}$, $I_{rr}=0.25\text{A}$

(2) Measured at 1.0MHz and applied reverse voltage of 4.0 volts

RATINGS AND CHARACTERISTIC CURVES

FIG. 1 - TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC



NOTES: 1. Rise Time = 7ns max. Input Impedance = 1 megohm, 22pF.
2. Rise Time = 10ns max. Source Impedance = 50 ohms.

FIG. 2 - TYPICAL FORWARD CURRENT DERATING CURVE

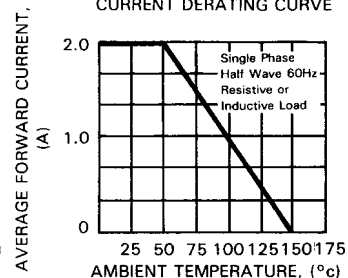


FIG. 3 - TYPICAL REVERSE CHARACTERISTICS

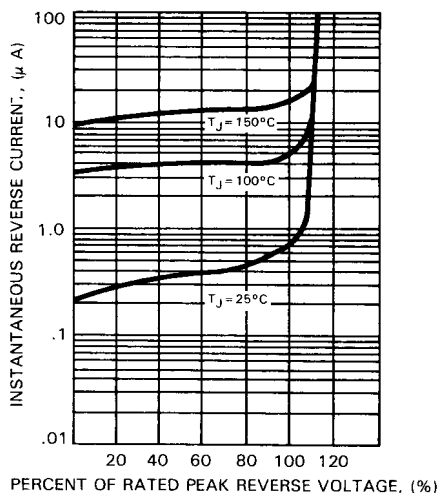


FIG. 5 - MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

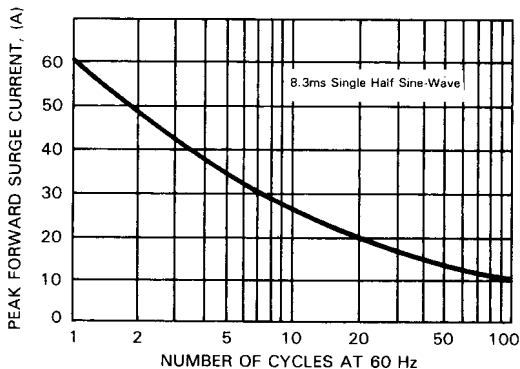


FIG. 4 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

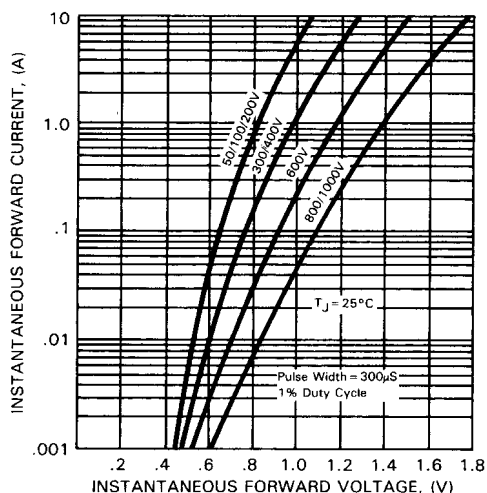


FIG. 6 - TYPICAL JUNCTION CAPACITANCE

